iC-PN2624 pre PHASED ARRAY NONIUS ENCODER 26-1024



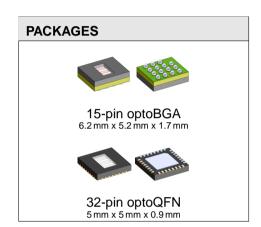
Absolute position encoders

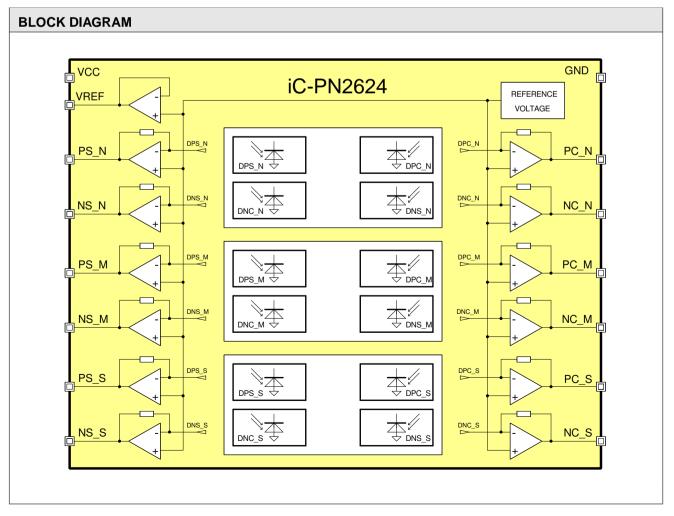
APPLICATIONS

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FEATURES

Compact photosensor for high-resolution nonius scanning Phased-array design for 1023/1024/992 PPR (N/M/S channel) with excellent signal matching Reduced cross talk due to moderate track pitch Ultra low dark currents for operation to high temperature Low noise amplifiers with high transimpedance of typ. 4 M Ω Short-circuit-proof, low impedance voltage outputs for enhanced EMI tolerance Space saving optoQFN and optoBGA packages (RoHS compliant) Low power consumption from single 4.5 to 5.5 V supply Operational temperature range of -40 to +110 °C Suitable code disc: LSHC1S 26-1024N (glass 1 mm) OD \emptyset 26 mm, ID \emptyset 11.6 mm, optical radius 10.905 mm







DESCRIPTION

The optical encoder iC-PN2624 features monolithically integrated photosensors arranged in a phasedarray.

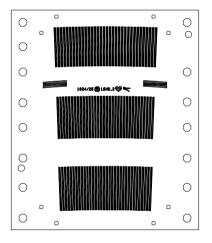
A high transimpedance gain of typically $4 M\Omega$ generates output signals of a few hundret millivolts already from illumination levels of 1 to $3 \,\text{mW/cm}^2$. In most cases no additional measures must be considered to filter for noise and interferences.

Analog nonius encoders are the typical application for iC-PN2624. Its 3-track scanning features a phased-array of multiple photosensors each per track, generating positive and negative going sine signals, as well as positive and negative going cosine signals. An excellent matching and common mode behavior of the differential signal paths is obtained by a paired amplifier design, reducing the needs for external signal calibration to an absolute minimum.

The spectral sensitivity range includes visible to near infrared light, with the maximum sensitivity being close to a wavelength of 680 nm. An output voltage of approximately 1 V is typical under low light conditions, for instance when iC-PN2624 is illuminated at only 1.5 mW/cm^2 by an 740 nm LED.

PACKAGES INFORMATION

PAD LAYOUT (2.88 mm x 3.37 mm)



PAD FUNCTIONS No. Name Function

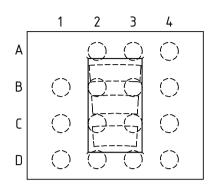
- 1 VCC +4.5..5.5 V Supply Voltage
- 2 VREF Reference Voltage Output
- 3 PS N N-Track Sine +
- 4 NS N N-Track Sine -
- 5 PS M M-Track Sine +
- 6 NS M M-Track Sine -
- 7 PS S S-Track Sine +
- 8 NS S S-Track Sine -
- 9 NC S S-Track Cosine -
- 10 PC S S-Track Cosine +
- 11 NC_M M-Track Cosine -
- 12 PC M M-Track Cosine +
- 13 NC N N-Track Cosine -
- 14 PC N N-Track Cosine +
- 15 GND Ground

All outputs are analog voltage outputs.



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PIN CONFIGURATION oBGA LSH2C (6.2 mm x 5.2 mm)

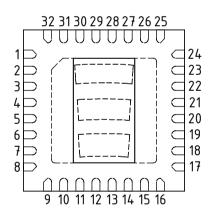


PIN FUNCTIONS

No. Name Function

A2	VCC	+4.55.5 V Supply Voltage
A3	VREF	Reference Voltage Output
A4	GND	Ground
B1	PS_N	N-Track Sine +
B2	NS_N	N-Track Sine -
В3	NC_N	N-Track Cosine -
Β4	PC_N	N-Track Cosine +
C1	PS_M	M-Track Sine +
C2	NS_M	M-Track Sine -
C3	NC_M	M-Track Cosine -
C4	PC_M	M-Track Cosine +
D1	PS_S	S-Track Sine +
D2	NS_S	S-Track Sine -
D3	NC_S	S-Track Cosine -
D4	PC_S	S-Track Cosine +

PIN CONFIGURATION oQFN32-5x5 (5 mm x 5 mm)



Package qualification optoQFN32-5x5 pending.

PIN FUNCTIONS

No. Name Function

- 1 VCC +4.5..5.5 V Supply Voltage
- 2 VREF Reference Voltage Output
- 3 PS_N N-Track Sine +
- 4 NS_N N-Track Sine -
- 5 PS_M M-Track Sine +
- 6 NS M M-Track Sine -
- 7 PS S S-Track Sine +
- 8 NS S S-Track Sine -
- 17 NC_S S-Track Cosine -
- 18 PC_S S-Track Cosine +
- 19 NC_M M-Track Cosine -
- 20 PC_M M-Track Cosine +
- 21 NC_N N-Track Cosine -
- 22 PC_N N-Track Cosine +
- 24 GND Ground
 - BP Backside pad (oQFN32-5x5 only): not intended as an electrical connection point; when using as shield a single link to GND is permissible.

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ABSOLUTE MAXIMUM RATINGS

These ratings do not imply operating conditions; functional operation is not guaranteed. Beyond these ratings device damage may occur.

ltem	Symbol	Parameter	Conditions			Unit
No.				Min.	Max.	
G001	VCC	Voltage at VCC		-0.3	6	V
G002	I(VCC)	Current in VCC		-20	20	mA
G003	V()	Pin Voltage, all signal outputs		-0.3	VCC + 0.3	V
G004	I()	Pin Current, all signal outputs		-20	20	mA
G005	Vd()	ESD Susceptibility, all pins	HBM, 100 pF discharged through $1.5 \text{k}\Omega$		2	kV
G006	Tj	Junction Temperature		-40	150	°C
G007	Ts	Chip Storage Temperature		-40	150	°C

THERMAL DATA

Item	Symbol	Parameter	Conditions				Unit
No.	-,			Min.	Тур.	Max.	
T01	Та	Operating Ambient Temperature Range		-40		110	°C
			package oQFN32-5x5*	-40		110*	°C
			(extended temperature range on request)				
T02	Ts	Storage Temperature Range	package oBGA LSH2C,	-40		110	°C
			package oQFN32-5x5*	-40		110*	°C
T03	Tpk	Soldering Peak Temperature	package oBGA LSH2C				
			tpk < 20 s, convection reflow			245	°C
			tpk < 20 s, vapor phase soldering			230	°C
			TOL (time on label) 8 h;				
			Please refer to customer information file No. 7 for details.				
T04	Tpk	Soldering Peak Temperature	package oQFN32-5x5*				
			tpk < 20 s, convection reflow			245	°C
			tpk < 20 s, vapor phase soldering			230	°C
			MSL 5A (max. floor live 24 h at 30 °C and				
			60 % RH); Please refer to customer information file No. 7				
			for details.				

*) Package qualification pending.

All currents flowing into the device pins are positive; all currents flowing out of the device pins are negative.

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ELECTRICAL CHARACTERISTICS

ltem No.	Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
	Device				71		
001	VCC	Permissible Supply Voltage		4.5		5.5	V
002	I(VCC)	Supply Current in VCC	no output load, photocurrents within linear op- erating range (no override)		9.5	15	mA
003	Vc()hi	Clamp-Voltage hi at all pins	I() = 4 mA			11	V
004	Vc()lo	Clamp-Voltage lo at all pins	I() = -4 mA	-1.2		-0.3	V
Photo	sensors	1					
101	λ ar	Spectral Application Range	$Se(\lambda ar) = 0.25 \times S(\lambda)max$	400		950	nm
102	λ pk	Peak Sensitivity Wavelength			680		nm
103	Aph()	Radiant Sensitive Area			0.1		mm ²
104	$S(\lambda)$	Spectral Sensitivity	$\lambda_{\text{LED}} = 740 \text{nm}$		0.5		A/W
105	S(\lambda pk)max	Maximum Spectral Sensitivity	$\lambda_{\text{LED}} = \lambda pk$		0.55		A/W
106	E()mxr	Irradiance For Maximum Signal Level	λ_{LED} = 740 nm, Vout() not saturated	0.9	1.6	2.3	mW/ cm ²
Photo	current Am	blifiers	1		1		1
201	lph()	Permissible Photocurrent Operat- ing Range		0		280	nA
202	η()r	Photo Sensitivity (light-to-voltage conversion ratio)	$\lambda_{\text{LED}} = 740 \text{nm}$	0.8	1.2	2.0	V/µW
203	Z()	Equivalent Transimpedance Gain	Z = Vout() / Iph()	2.69	4.0	5.46	MΩ
204	TCz	Temperature Coefficient of Tran- simpedance Gain			-0.12		%/°C
209	ΔZ()pn	Transimpedance Gain Matching	P vs. N path per diff. channel	-0.2		0.2	%
210	∆Vout()pn	Signal Matching	no illumination, any output to any output	-35		35	mV
211	Δ Vout()pn	Signal Matching	no illumination, P. output vs. corresponding N. output	-2.5		2.5	mV
212	fc()hi	Cut-off Frequency (-3 dB)		120	180	280	kHz
213	VNoise()	RMS Output Noise	illuminated to 500 mV signal level above dark level, 500 kHz band width		0.5		mV
Signa	Outputs						
301	Vout()mx	Permissible Maximum Output Voltage	illumination to E()mxr, linear gain	2.45	2.72	3.02	V
302	Vout()d	Dark Signal Level	no illumination, load 20 kΩ vs. +2 V	600	770	1000	mV
303	Vout()acmx	Maximum Signal Level	Vout()acmx = Vout()mx - Vout()d	1.48	1.96	2.35	V
304	lsc()hi	Short-Circuit Current hi	load current to ground	100	420	800	μA
305	lsc()lo	Short-Circuit Current lo	load current to IC	250	480	700	μA
306	Ri()	Internal Output Resistance	f = 1 kHz	70	110	180	Ω
307	ton()	Power-On Settling Time	$VCC = 0 V \rightarrow 5 V$			100	μs
Refer	ence Voltage	VREF					
401	VREF	Reference Voltage	I(VREF) = 0+1.6 mA	600	770	1000	mV
402	dVout()	Load Balancing	I(VREF) = 0+1.6 mA	-10		+10	mV
403	lsc()hi	Short-Circuit Current hi	load current to ground	200	420	800	μA
404	lsc()lo	Short-Circuit Current lo	load current to IC	2	4.5	10	mA



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APPLICATION CIRCUITS

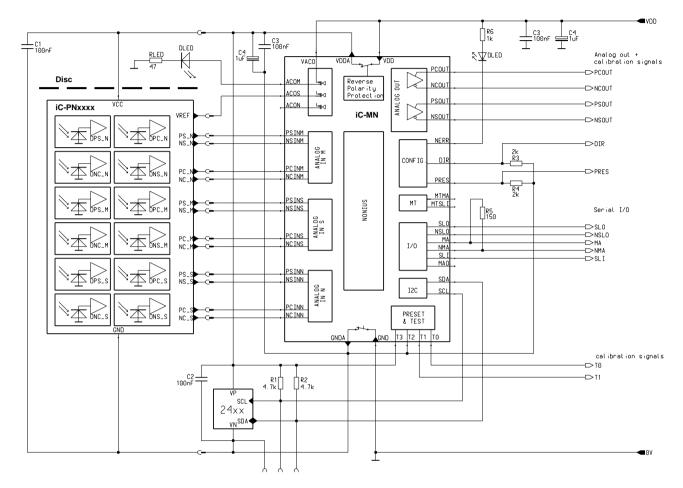


Figure 1: Application example of absolute encoder circuit.

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We understand suitable application of our published designs to be state-of-the-art technology which can no longer be classed as inventive under the stipulations of patent law. Our explicit application notes are to be treated only as mere examples of the many possible and extremely advantageous uses our products can be put to.

iC-PN2624

PHASED ARRAY NONIUS ENCODER 26-1024



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ORDERING INFORMATION

Туре	Package	Options	Order Designation
iC-PN2624	-		iC-PN2624 chip
	15-pin optoBGA, 6.2 mm x 5.2 mm thickness 1.7 mm		iC-PN2624 oBGA LSH2C
	32-pin optoQFN, 5 mm x 5 mm, thickness 0.9 mm		iC-PN2624 oQFN32-5x5
		Suitable code disc	
		1023/1024/992 PPR OD \varnothing 26 mm, ID \varnothing 11.6 mm, optical radius 10.905 mm (glass 1 mm)	

For technical support, information about prices and terms of delivery please contact:

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